

Kerr effect in layered nanostructures

Gábor Széchenyi and József Cserti

Department of Physics of Complex Systems,
Eötvös Loránd University
Budapest, Hungary

Poznan, NanoCTM
24th September, 2013

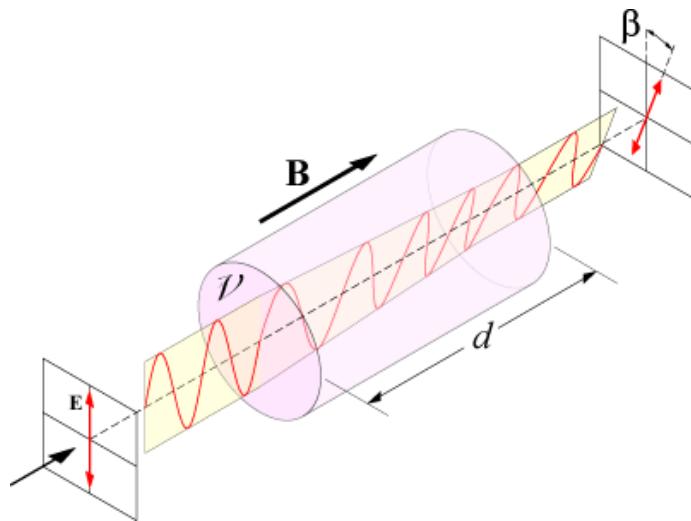


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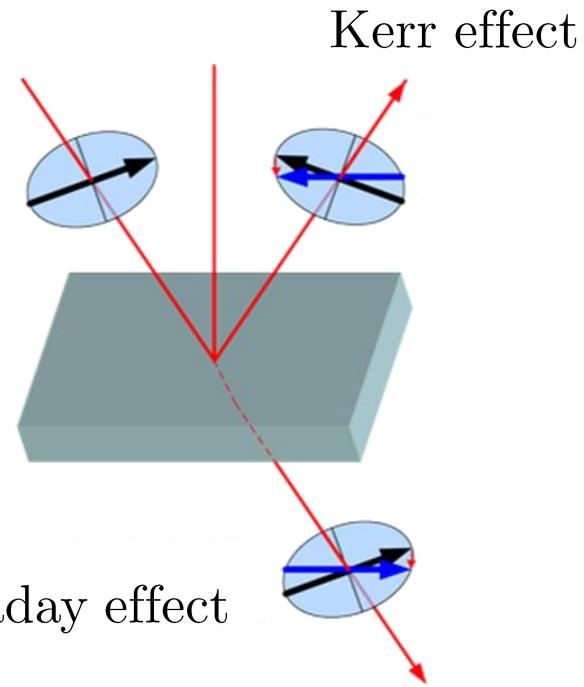
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- Transfer matrix method
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Faraday and Kerr effects

Magneto-optical phenomenon
Rotation of the plane of polarization



Faraday effect



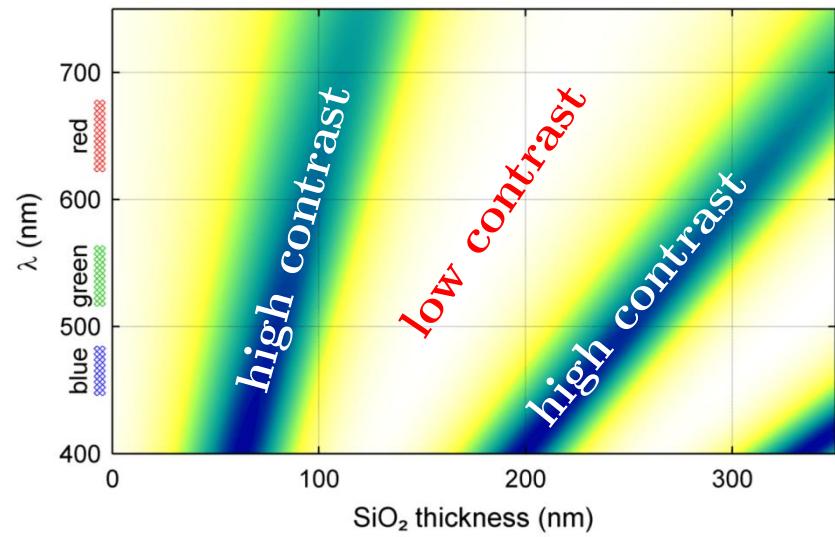
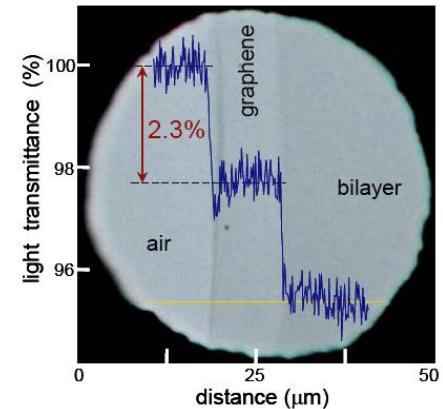
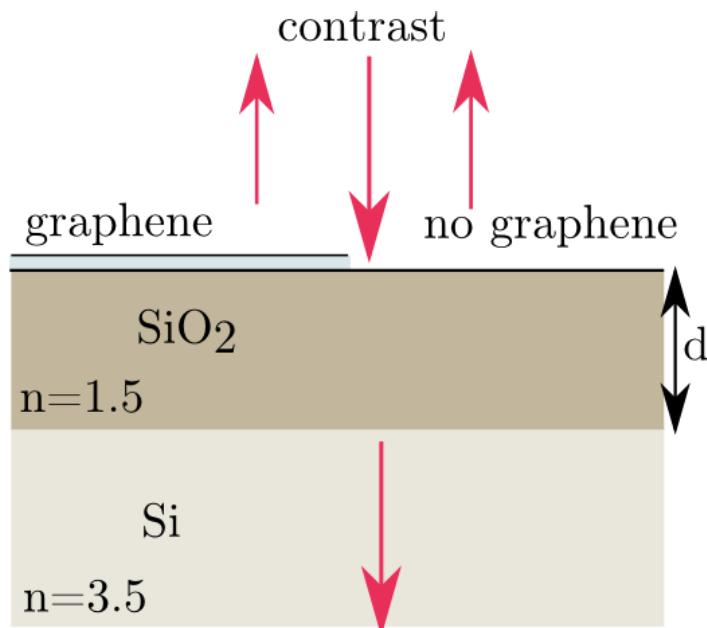
Faraday effect

Broken time-reversal symmetry

Motivation

Graphene visibility

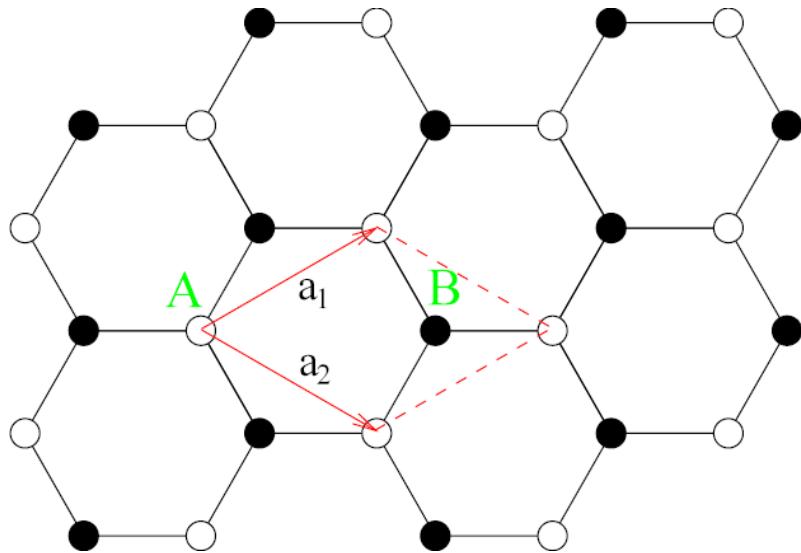
- K. S. Novoselov ,et al., Science 306, 666 (2004)
- R.R. Nair et al., Science 320, 1308 (2008)
- P. Blake, et al., Appl. Phys. Lett. 91, 063124 (2007)



Kerr effect

Is Kerr-effect relevant in graphene nanostructures?
Calculating Kerr-effect in layered nanostructures.

Graphene

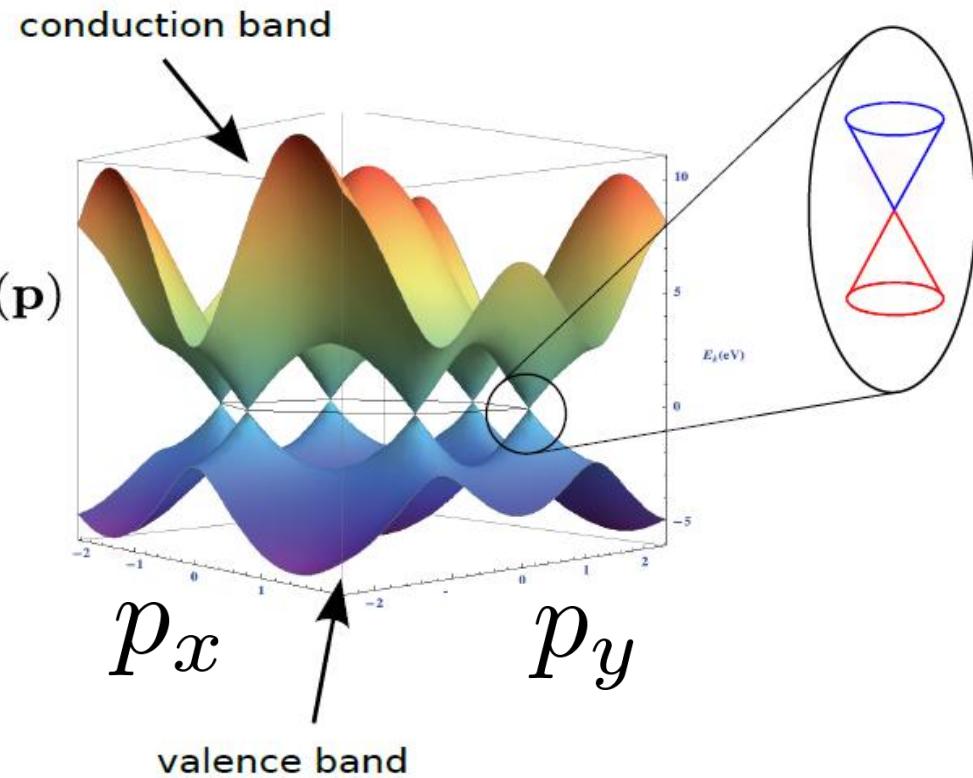


Hamiltonian: $H = v\mathbf{p}\boldsymbol{\sigma}$

Complex conductivity:

$$\sigma_{\alpha\beta}(\omega) = \frac{e^2}{4\hbar} \delta_{\alpha\beta} \left(4\mu\delta(\hbar\omega) + \Theta(\hbar\omega - 2\mu) + i\frac{4\mu}{\pi\hbar\omega} - \frac{i}{\pi} \log \frac{\hbar\omega+2\mu}{\hbar\omega-2\mu} \right)$$

Diagonal \rightarrow No Kerr

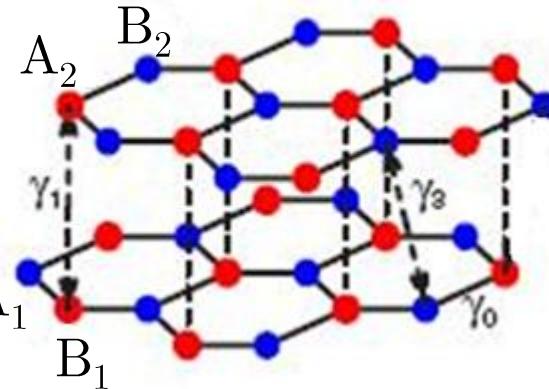


Chemical potential

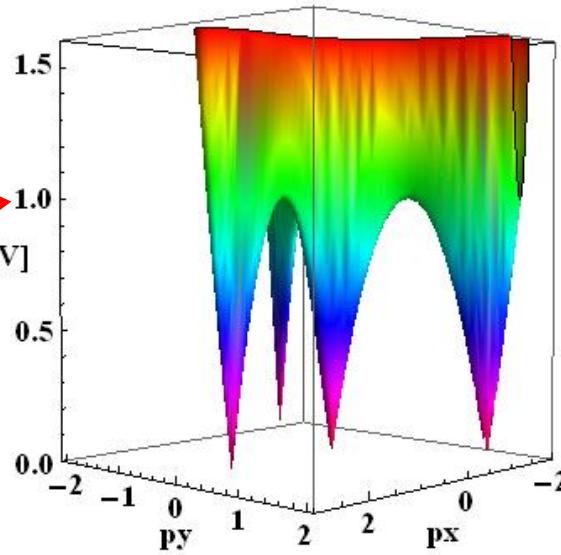
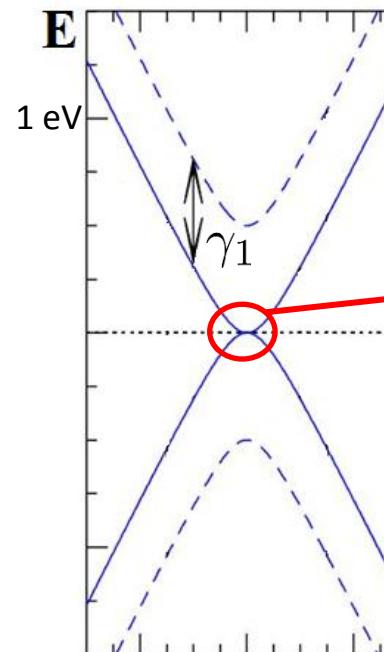
Bilayer graphene

Hamiltonian:

$$\hat{H} = \begin{pmatrix} 0 & \beta vp_+ & 0 & vp_- \\ \beta vp_- & 0 & vp_+ & 0 \\ 0 & vp_- & 0 & \gamma_1 \\ vp_+ & 0 & \gamma_1 & 0 \end{pmatrix} \begin{pmatrix} A_1 \\ B_2 \\ A_2 \\ B_1 \end{pmatrix}$$



Dispersion relation:



Trigonal warping

- $v = 3.7 \cdot 10^{-3} c$
- $v = \frac{\sqrt{3}a\gamma_0}{2\hbar}$
- $\gamma_1 = 0.39 eV$
- $p_{\pm} = p_x \pm ip_y$
- $\beta = \frac{\gamma_3}{\gamma_0} \approx 0.1$

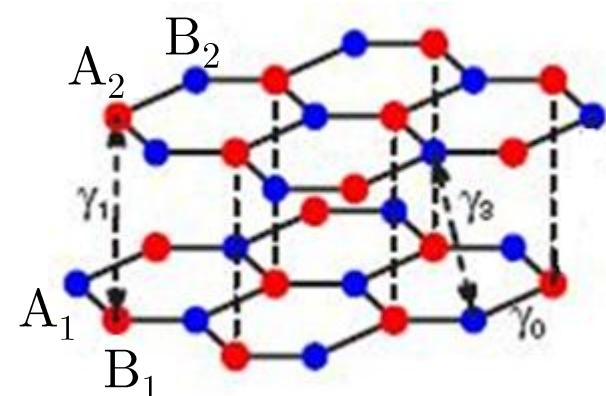
Neglect: $\beta=0$

Broken symmetry in bilayer graphene

Order parameter

$$\hat{H} = \xi \begin{pmatrix} \Delta_{\xi s} & 0 & 0 & v_F p_- \\ 0 & -\Delta_{\xi s} & v_F p_+ & 0 \\ 0 & v_F p_- & 0 & \xi \gamma_1 \\ v_F p_+ & 0 & \xi \gamma_1 & 0 \end{pmatrix} \begin{pmatrix} A_1 \\ B_2 \\ A_2 \\ B_1 \end{pmatrix}$$

Valley quantum number ± 1



$$\Delta_{\xi s} = \Delta_{\text{QVH}} + s\Delta_{\text{LAF}} + \xi\Delta_{\text{QAH}} + s\xi\Delta_{\text{QSH}}$$

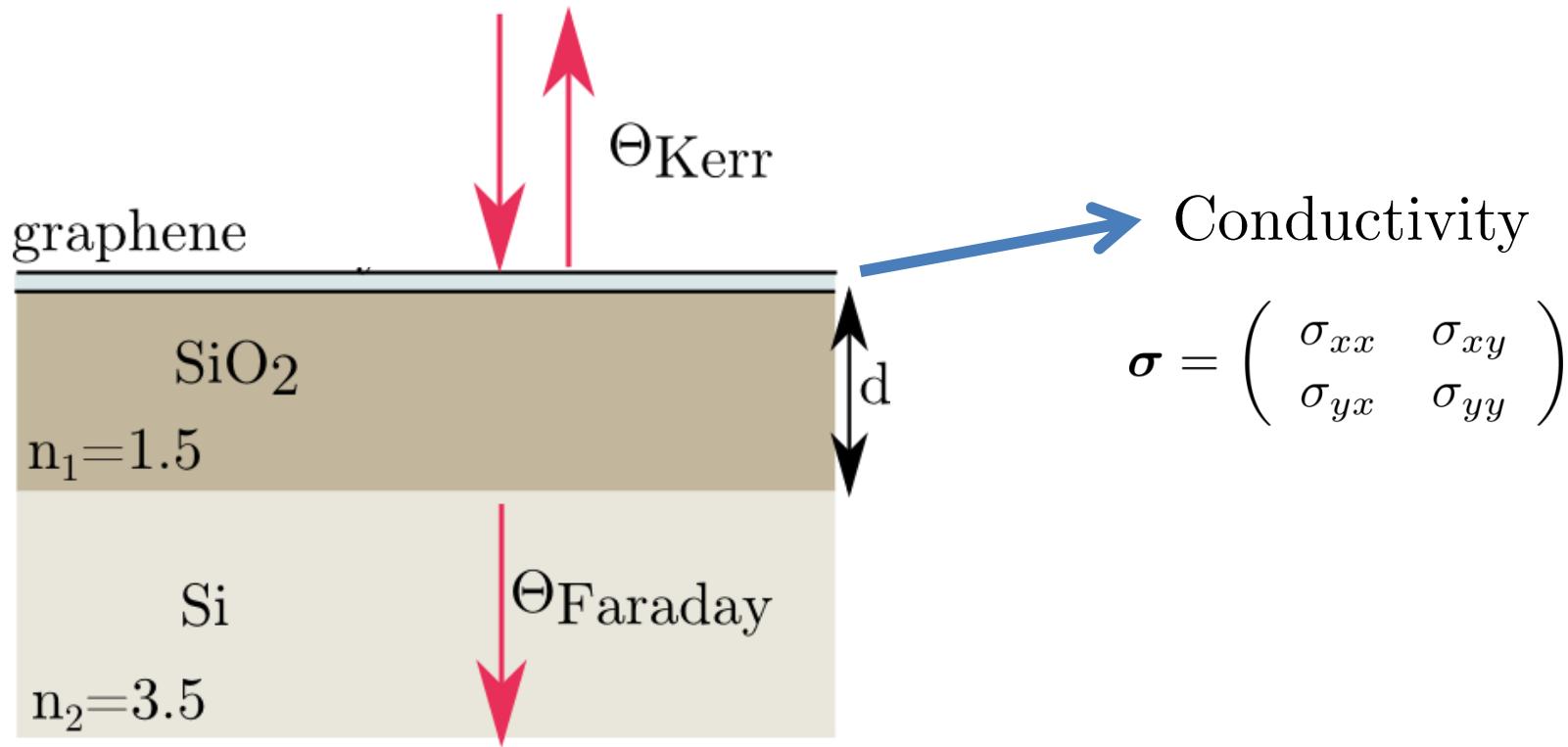
Possible gapped states in bilayer graphene at neutral point:

| Ordered state | Order parameter |
|---------------|---|
| QVH | $\langle \psi_{A1Ks}^\dagger \psi_{A1Ks} + \psi_{A1K's}^\dagger \psi_{A1K's} - \psi_{B2Ks}^\dagger \psi_{B2Ks} - \psi_{B2K's}^\dagger \psi_{B2K's} \rangle$ |
| LAF | $\langle \psi_{A1Ks}^\dagger s \psi_{A1Ks} + \psi_{A1K's}^\dagger s \psi_{A1K's} - \psi_{B2Ks}^\dagger s \psi_{B2Ks} - \psi_{B2K's}^\dagger s \psi_{B2K's} \rangle$ |
| QAH | $\langle \psi_{A1Ks}^\dagger \psi_{A1Ks} - \psi_{A1K's}^\dagger \psi_{A1K's} - \psi_{B2Ks}^\dagger \psi_{B2Ks} + \psi_{B2K's}^\dagger \psi_{B2K's} \rangle$ |
| QSH | $\langle \psi_{A1Ks}^\dagger s \psi_{A1Ks} - \psi_{A1K's}^\dagger s \psi_{A1K's} - \psi_{B2Ks}^\dagger s \psi_{B2Ks} + \psi_{B2K's}^\dagger s \psi_{B2K's} \rangle$ |

- E. V. Gorbar ,et al., PRB 86, 075414 (2012)
- R. Nandkishore, et al., PRL 107, 097402 (2011)

Transfer matrix method I.

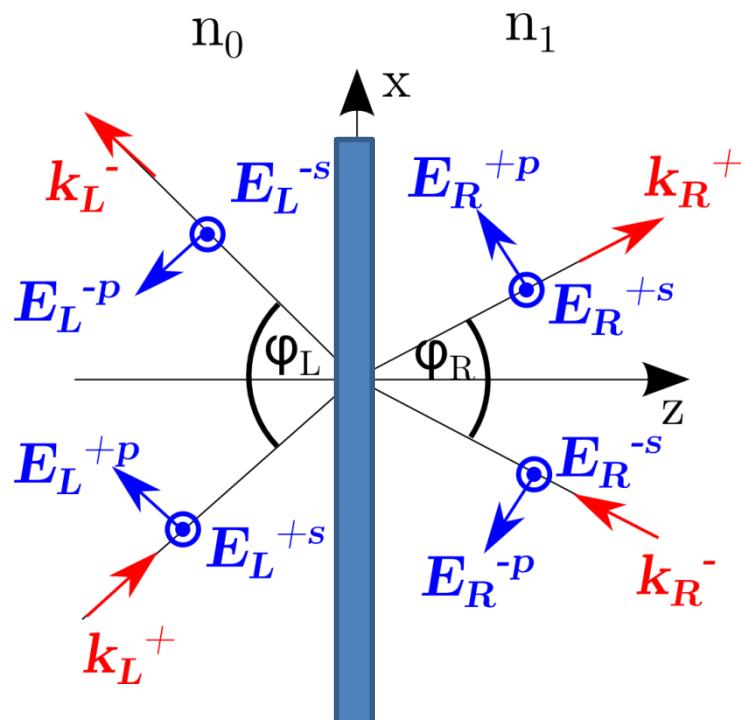
Example:



Structure of transfer matrix:

$$\mathbf{M}_{\text{jump}}(n_1, n_2) \mathbf{M}_{\text{propagate}}(n_1, d) \mathbf{M}_{\text{jump}}(n_0, n_1, \boldsymbol{\sigma})$$

Transfer matrix method II.



Graphene as a boundary

Boundary condition:

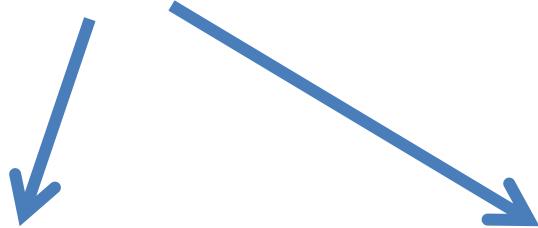
$$\begin{aligned}\text{rot} \mathbf{H} &= \sigma \mathbf{E} + \frac{\partial \mathbf{D}}{\partial t} \\ \text{rot} \mathbf{E} &= -\frac{\partial \mathbf{B}}{\partial t}\end{aligned}$$

$$\begin{pmatrix} E_R^{+s} \\ E_R^{+p} \\ E_R^{-s} \\ E_R^{-p} \end{pmatrix} = \mathbf{M}_{\text{jump}} \begin{pmatrix} E_L^{+s} \\ E_L^{+p} \\ E_L^{-s} \\ E_L^{-p} \end{pmatrix}$$

$\sigma_{xy} = 0 \longrightarrow$ No coupling between p and s mode
No Kerr rotation

Transfer matrix method III.

$$\mathbf{M}_{\text{total}} = \mathbf{M}_{\text{jump}}(n_1, n_2) \mathbf{M}_{\text{propagate}}(n_1, d) \mathbf{M}_{\text{jump}}(n_0, n_1, \sigma)$$



$$\mathbf{t} = \begin{pmatrix} t_{ss} & t_{sp} \\ t_{ps} & t_{pp} \end{pmatrix} \quad \mathbf{r} = \begin{pmatrix} r_{ss} & r_{sp} \\ r_{ps} & r_{pp} \end{pmatrix}$$



Faraday effect

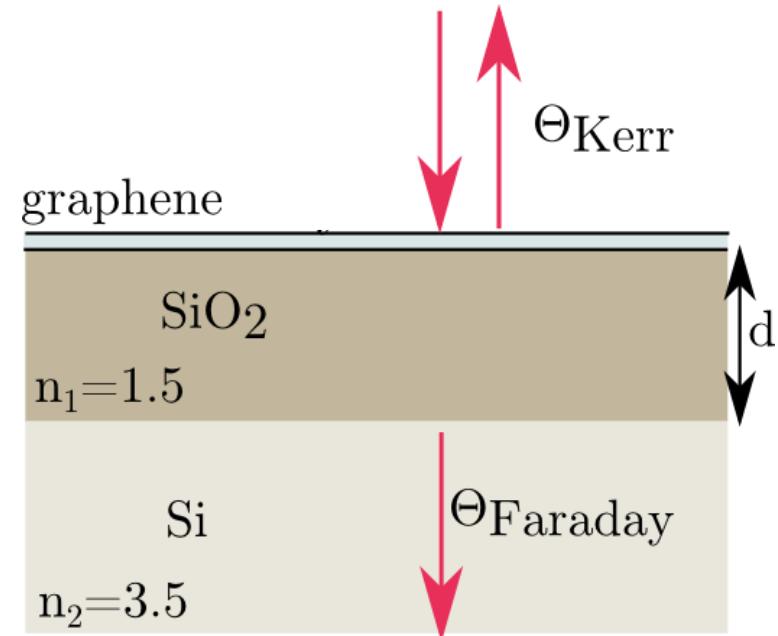


Kerr effect

$$\Theta_{\text{Faraday}} = \text{Re} \left[\frac{t_{sp}}{t_{pp}} \right]$$

$$\Theta_{\text{Kerr}} = \text{Re} \left[\frac{r_{sp}}{r_{pp}} \right]$$

Need σ_{xy} !!



Kerr angle

Kerr angle at perpendicular incidence

$$k = \frac{n_1}{\omega c}$$

$$\Theta_{Kerr} = \frac{(n_1 + e^{2ikd}(n_1 - n_2) + n_2)^2}{(e^{2ikd}(1+n_1)(n_1-n_2) - (n_1-1)(n_1+n_2))(e^{2ikd}(1-n_1)(n_1-n_2) + (n_1+1)(n_1+n_2))} \operatorname{Re} \left[\frac{\sigma_{xy}}{\epsilon_0 c} \right]$$

1) $d = \frac{n\pi}{k} \quad n \in \mathbb{N}$

$$\Theta_{Kerr} = \frac{2}{1-n_2^2} \operatorname{Re} \left[\frac{\sigma_{xy}}{\epsilon_0 c} \right]$$

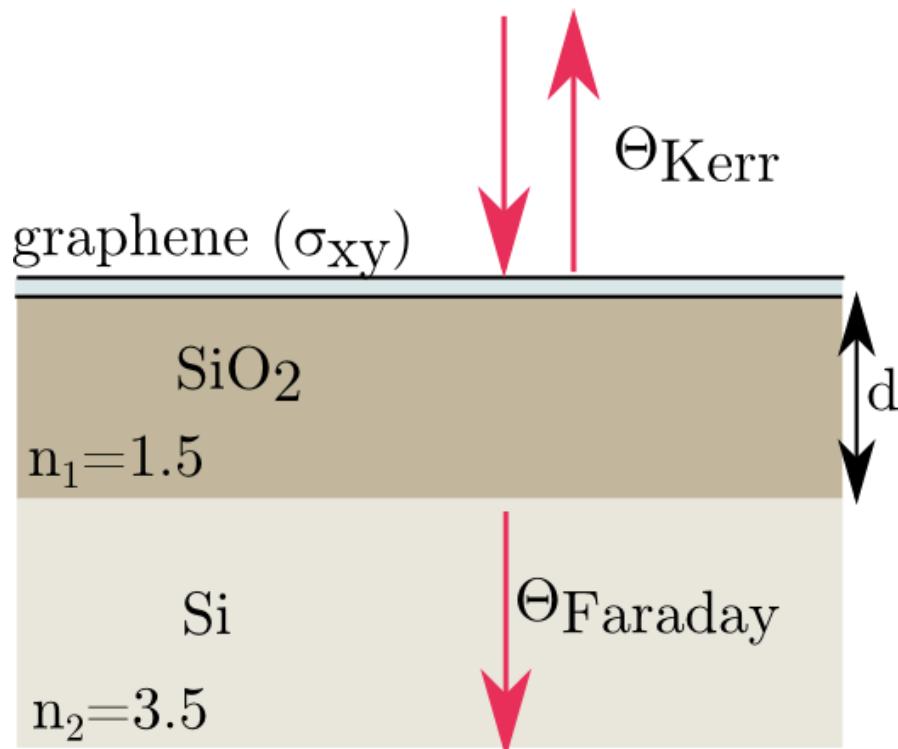
Large Kerr rotation if: $n_2 = 1$

Free-standing graphene

2) $d = \frac{\pi}{2k} + \frac{n\pi}{k} \quad n \in \mathbb{N}$

$$\Theta_{Kerr} = \frac{2n_2^2}{n_2^2 - n_1^4} \operatorname{Re} \left[\frac{\sigma_{xy}}{\epsilon_0 c} \right]$$

Large Kerr rotation if: $n_1 = \sqrt{n_2}$



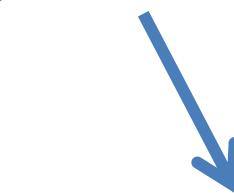
Optical Hall conductivity

Current-current correlation function

$$\Pi_{xy}(i\omega) = \frac{1}{V\beta} \sum_{\mathbf{k},n} \text{Tr} \left[\frac{\partial H}{\partial p_x} G(\mathbf{k}, i\omega_n + i\omega) \frac{\partial H}{\partial p_y} G(\mathbf{k}, i\omega_n) \right],$$

Green's function

$$G(\mathbf{k}, i\omega_n) = \frac{1}{i\omega_n - H}$$



Matsubara frequency

Complex conductivity

$$\sigma_{xy}(\omega) = \frac{ie^2}{\omega} \Pi_{xy}(i\omega \rightarrow \omega + i\eta)$$



Zero approximation of self-energy

Numerically versatile method using projectors

Hall conductivity of bilayer graphene

QAH state in bilayer graphene: $\hat{H} = \xi \begin{pmatrix} \Delta_{\xi s} & 0 & 0 & v_F p_- \\ 0 & -\Delta_{\xi s} & v_F p_+ & 0 \\ 0 & v_F p_- & 0 & \xi \gamma_1 \\ v_F p_+ & 0 & \xi \gamma_1 & 0 \end{pmatrix}$

$$\Delta_{\xi s} = \xi \Delta_{QAH}$$

Eigenvalues:

$$E_{1,2}^2 = v_F^2 p^2 + \frac{\Delta_{\xi s}^2 + \gamma_1^2}{2} \pm \sqrt{\frac{(\gamma_1^2 - \Delta_{\xi s}^2)^2}{4} + (\gamma_1^2 + \Delta_{\xi s}^2)v_F^2 p^2},$$

Current-current correlation function

$$\begin{aligned} \Pi_{xy}(i\omega) = & \sum_{\xi=\pm, s=\pm} \frac{i\xi \Delta_{\xi s}}{2\pi} \int_0^\infty p dp \left\{ \frac{(\gamma_1^2 - \Delta_{\xi s}^2)(E_1 + E_2)(\gamma_1^2 - p^2 - E_1 E_2)}{E_1 E_2 (E_1^2 - E_2^2)^2} \left(\frac{1}{i\omega + E_1 + E_2} + \frac{1}{i\omega - E_1 - E_2} \right) \right. \\ & \left. + \frac{4p^2 \gamma_1^2}{(E_1^2 - E_2^2)^2} \left[\frac{1}{E_1} \left(\frac{1}{i\omega + 2E_1} + \frac{1}{i\omega - 2E_1} \right) + \frac{1}{E_2} \left(\frac{1}{i\omega + 2E_2} + \frac{1}{i\omega - 2E_2} \right) \right] \right\}. \end{aligned}$$

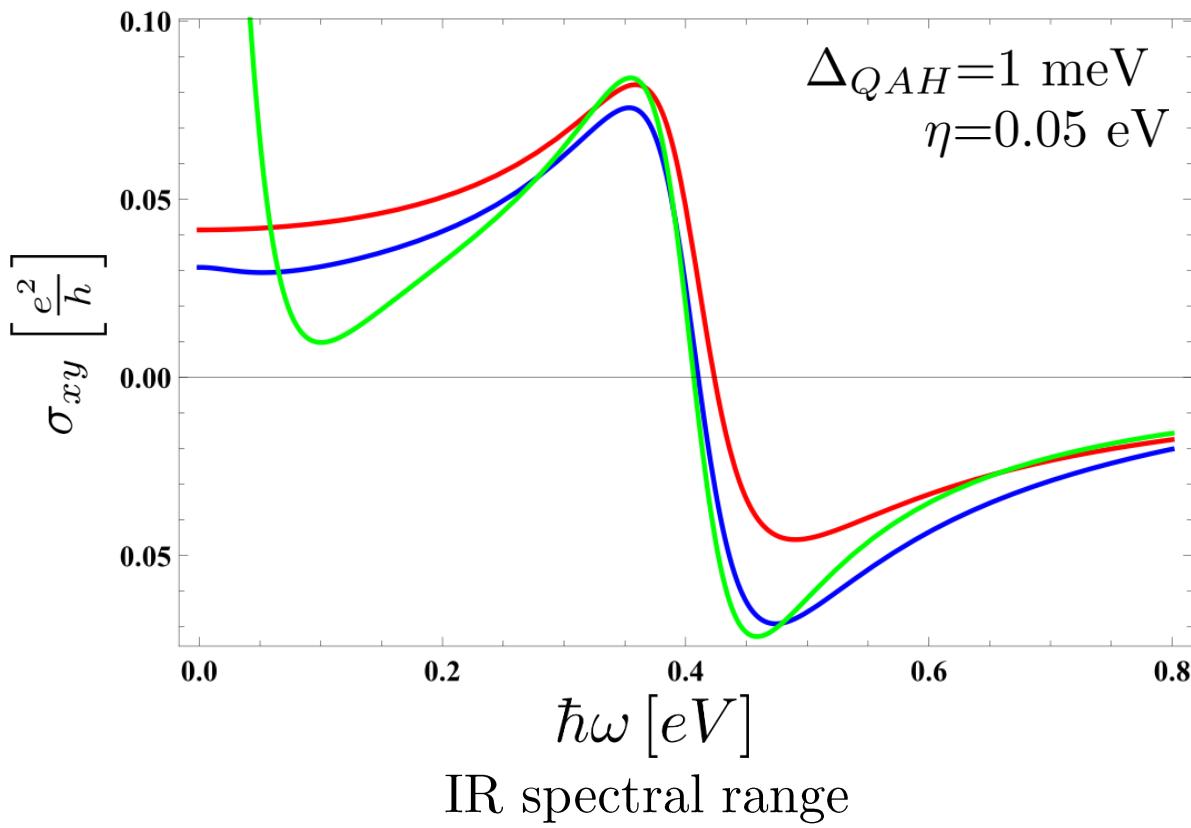
Complex Hall conductivity

$$\sigma_{xy}(\omega) = \frac{ie^2}{\omega} \Pi_{xy}(i\omega \rightarrow \omega + i\eta)$$

Hall conductivity of bilayer graphene

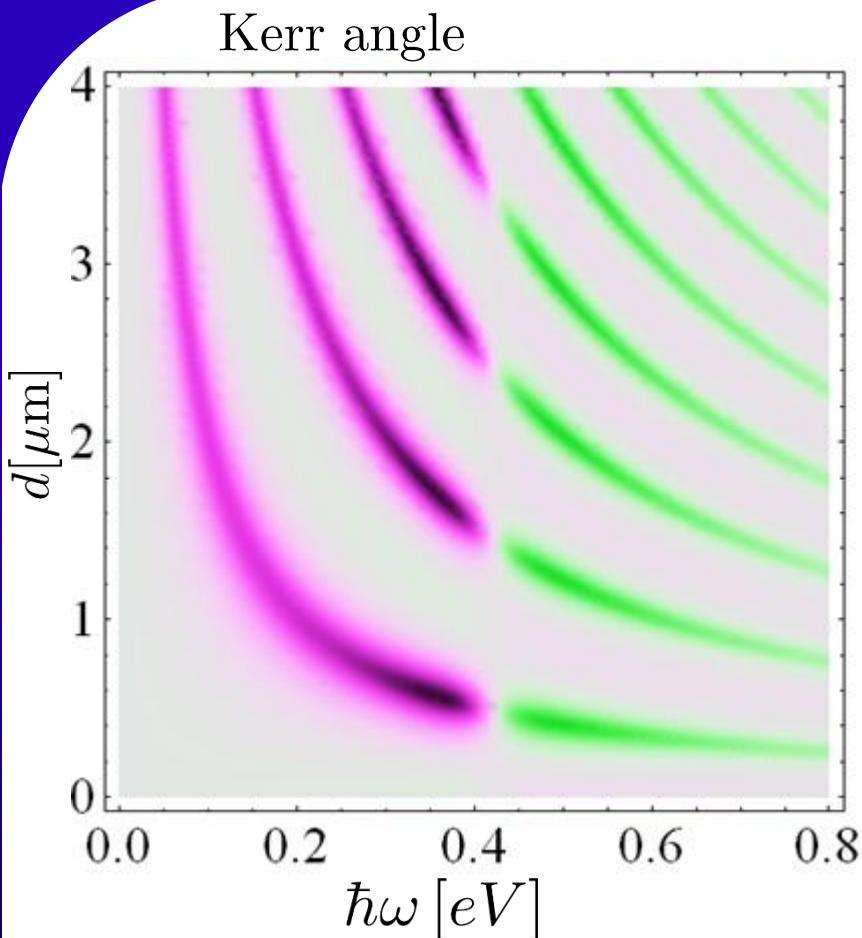
$$\hat{H} = \xi \begin{pmatrix} \Delta_{\xi s} & 0 & 0 & v_F p_- \\ 0 & -\Delta_{\xi s} & v_F p_+ & 0 \\ 0 & v_F p_- & 0 & \xi \gamma_1 \\ v_F p_+ & 0 & \xi \gamma_1 & 0 \end{pmatrix}$$

$$\Delta_{\xi s} = \xi \Delta_{QAH}$$



Differences?

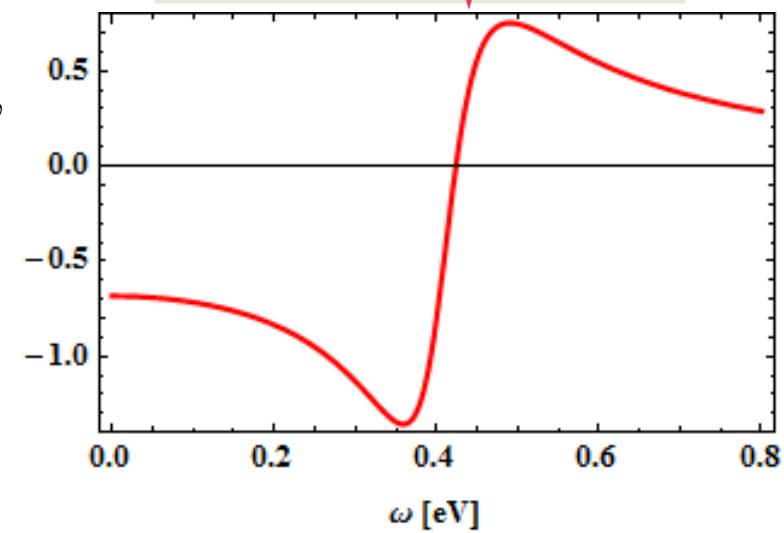
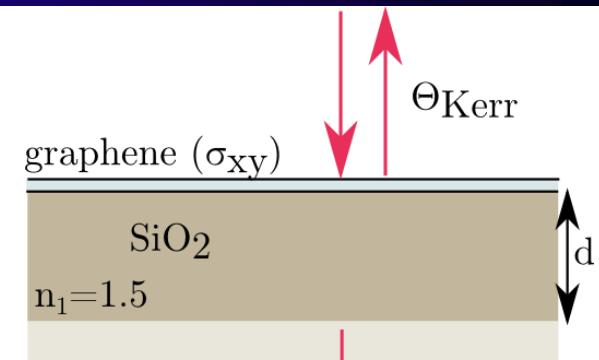
Kerr angle in bilayer graphene



Large Kerr angle lines:

$$d = \frac{\pi}{2k} + \frac{n\pi}{k} \quad n \in \mathbb{N}$$

$$\Theta_{Kerr} = \frac{2n_2^2}{n_2^2 - n_1^4} \operatorname{Re} \left[\frac{\sigma_{xy}}{\epsilon_0 c} \right]$$



free-standing graphene

Experimentally relevant regime,
sensitivity 0.001 deg

Conclusion

- Practical method to calculate Kerr angle in layered nanostructures
 - Transfer matrix method
- Optical Hall conductivity
 - Bilayer graphene
 - Broken symmetry
- Example: SiO₂, Si substrate
- Spectroscopic method of identifying phase of bilayer graphene

Acknowledgement:

József Cserti



Thanks for your attention!